

REMARKS

The Examiner is thanked for the thorough review and consideration of the present application. The Office Action dated June 1, 2006 has been received and its contents carefully reviewed.

Claims 54-71 are currently pending in the present application, of which claims 63-71 are withdrawn from consideration due to the constructive election in the outstanding Office Action. Reexamination and reconsideration of the application are respectfully requested.

In the Office Action, the Examiner rejected claims 54-62 under 35 U.S.C. § 103(a) as being unpatentable over Okibayashi et al. (U.S. Patent No. 5,504,599) in view of Yokoyama et al. (U.S. Patent No. 6,507,379). Applicants respectfully traverse this rejection.

Claim 54 is allowable over the cited reference in that claim 54 recites a combination of elements including, for example, "...an inorganic insulating layer made of one of silicon oxide and silicon nitride on a first side of the first substrate; a light emitting structure including an organic light emitting layer on the inorganic insulating layer..." None of the cited references, singly or in combination, teaches or suggests at least these features of the claimed invention. Accordingly, Applicants respectfully submit that claim 54 and claims 55-62, which depend therefrom, are allowable over the cited references.

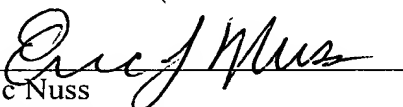
On page 4 of the Office Action, the Examiner cites Okibayashi et al. as teaching the aforementioned features recited in claim 54. In particular, the Examiner refers to the insulating layer 26 or the second insulating layer 31a in Figs. 1(1) and 1(2) of Okibayashi et al. as teaching the inorganic insulating layer made of one of silicon oxide and silicon nitride recited in claim 54. First of all, the second insulating layer 31a in Okibayashi et al. is a part of the EL light source. In contrast, the inorganic insulating layer in claim 54 is formed on the first substrate and the light emitting structure is then formed on the inorganic insulating layer. Secondly, the inorganic insulating layer in claim 54 is made of silicon oxide and silicon nitride. However, the insulating layer 26 in Okibayashi et al. is a bonding material formed of either silicone resin or oil, both of which are *organic* materials and different from the *inorganic* material of either silicon oxide or silicon nitride. See Okibayashi et al. at Col. 7, lines 38-56.

Applicants believe the application is in condition for allowance and early, favorable action is respectfully solicited. If the Examiner deems that a telephone conference would further the prosecution of this application, the Examiner is invited to call the undersigned attorney at the telephone number (202) 496-7500. All correspondence should continue to be sent to the below-listed address.

If these papers are not considered timely filed by the Patent and Trademark Office, then a petition is hereby made under 37 C.F.R. §1.136, and any additional fees required under 37 C.F.R. §1.136 for any necessary extension of time, or any other fees required to complete the filing of this response, may be charged to Deposit Account No. 50-0911. Please credit any overpayment to deposit Account No. 50-0911.

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Respectfully submitted,

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